

苏州敏芯微电子技术有限公司 MEMSensing Microsystems Co., Ltd

V 1.0 / Oct . 2016

MSM421A3729H9-C

Analog output MEMS microphone















# **GENERAL DESCRIPTION**

MSM421A3729H9-C is an omnidirectional, Top-ported, analog output MEMS microphone. It has high performance and reliability. It is with enhanced RF immunity performance.

MSM421A3729H9-C is available in a thin  $3.76 \text{ mm} \times 2.95 \text{ mm} \times 1.1 \text{ mm}$  metal cap LGA package. It is SMT compatible with no sensitivity degradation.

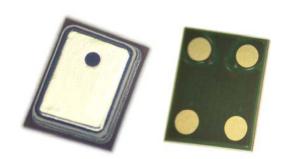
# **APPLICATIONS**

- ♦ Mobile Phone
- ♦ Laptop
- ♦ Tablet computer
- ♦ Bluetooth headset
- ♦ Earphone
- ♦ Wearable intelligent equipment

## **FEATURES**

- ♦ Low Noise
- ♦ Omnidirectional
- ♦ Excellent RF immunity
- ♦ Standard SMD Reflow
- Compatible with Sn/Pb and Pb-free solder processes
- ♦ RoHS/Halogen free compliant
- ♦ Sensitivity Matching within +/-1dB

#### **PRODUCT VIEW**





Parameter	Maximum value	Unit
Supply Voltage	-0.3 to 4.0	V
Sound Pressure Level	140	dB SPL
Mechanical Shock	10,000	g
Temperature Range	-40 to 100	°C
Electrostatic discharge protection	2 (HBM)	kV

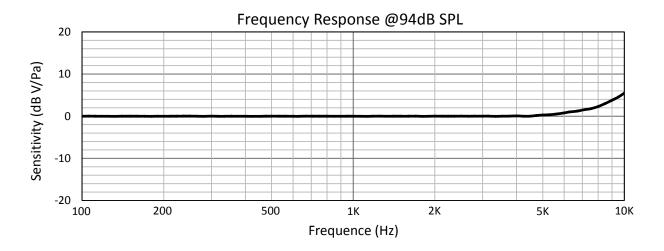
Stresses exceeding these "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation at these or any other conditions beyond those indicated under "Acoustic & Electrical Specifications" is not implied. Exposure beyond those indicated under "Acoustic & Electrical Specifications" for extended periods may affect device reliability.

## **ACOUSTIC & ELECTRICAL SPECIFICATIONS**

All data tak	en at 25°C, Re	elative Humidity	y 45±5% unles	ss otherwis	e specified
		Limits		unit	condition
	Min.	Nom.	Max.		
Directivity	(	Omni directiona	al		
Sensitivity	-43	-42	-41	dB	@1kHz ref 1V/Pa
Operation voltage	1.5	-	3.6	V	
Freq. range	Refer to the frequency response graphic			Hz	Ref to sensitivity@1kHz
Sensitivity loss across supply voltage	No change across the voltage range		dB		
Signal to noise ratio	-	59	-	dB	20 kHz bandwidth, A-weighted
THD	-	0.1	-	%	100dB SPL @1kHz S =Nom, Rload > 2 k
АОР	-	130	-	dB SPL	10% THD @1kHz S =Nom, Rload > 2 k
Polarity	Increasing output voltage			Increasing sound pressure	
Output impedance	- 200 -		Ω	@1kHz	
DC Output		0.7		V	
PSRR	-	70	-	dB	200mVpp sine wave @ 1 kHz, VDD = 1.8V
PSR	-	-100	-	dBV(A)	100 mVpp square wave@ 217 Hz, VDD = 1.8V, A-weighted
Current consumption	-	150	170	μΑ	
Storage temperature	-40	-	100	°C	

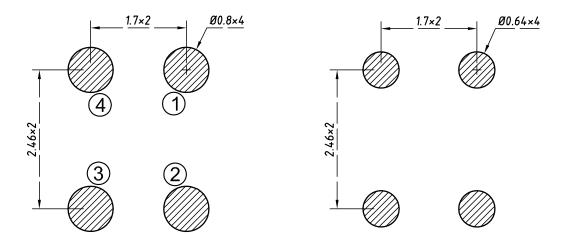


# **TYPICAL FREQUENCY RESPONSE**



## **SMT Parameters:**

1. Recommend PCB land pattern layout & Example solder stencil pattern: (unit: mm)





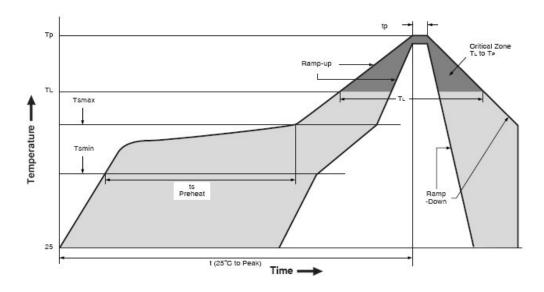








# 2. Recommend reflow profile:

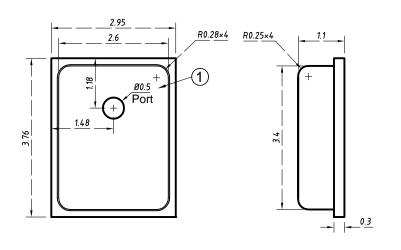


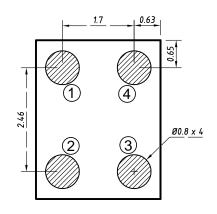
Description	Parameter	Pb-free
Average ramp-up rate	T <sub>smax</sub> to T <sub>P</sub>	3°C/sec max
Preheat		
Minimum temperature	T <sub>SMIN</sub>	150 °C
Maximum temperature	T <sub>SMAX</sub>	200 °C
Time(T <sub>SMIN</sub> to T <sub>SMAX</sub> )	t <sub>s</sub>	60 sec to 180 sec
Ramp-up rate	T <sub>SMAX</sub> to T <sub>L</sub>	1.25 °C/sec
Time maintained above liquidus temperature	t <sub>L</sub>	60 sec to 150 sec
Liquidus temperature	T <sub>L</sub>	217 °C
Peak temperature	T <sub>P</sub>	260 °C
Time within 5°C of actual peak temperature	t <sub>P</sub>	20 sec to 40 sec
Ramp-down rate	T <sub>P</sub> to T <sub>smax</sub>	6 °C/sec max
Time 25 °C (t25 °C) to peak temperature	t	8 minutes max



# **OUTLINE DIMENSIONS AND PIN DEFINITION:**







**BOTTOM VIEW** 

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TOP VIEW SIDE VIEW

PIN function description

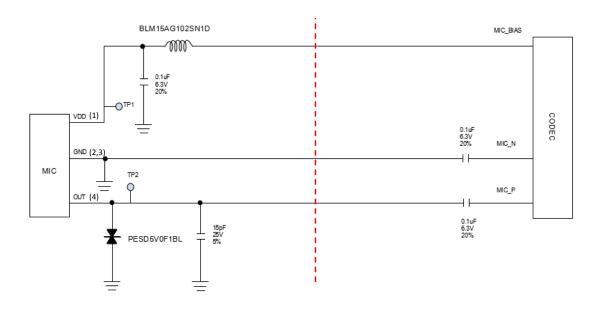
	·	
PIN#	Function	
1	VDD	
2	GND	
3	GND	
4	OUT	

Item	Dimension	Tolerance
Length (L)	3.76	±0.10
Width (W)	2.95	±0.10
Height (H)	1.10	±0.10
Acoustic Port (AP)	Ø0.5	±0.05

 $\label{eq:Dimensions} \mbox{ Dimensions are in millimeters }$   $\mbox{ Tolerance is $\pm 0.15 mm unless otherwise specified.}$ 

# **RECOMMENDED INTERFACE CIRCUIT:**

Recommended Application Example (differential amplification circuit)



NOTE: It is recommended that the components on the left side of red line be placed close to MIC, and components on the right side of red line be placed close to codec.







#### ADDITIONAL NOTES

- (A) MSL (moisture sensitivity level) Class 2a.
- (B) Maximum of 3 reflow cycles is recommended.
- (C) The ASIC of Top-ported microphone should be covered with
- (D) In order to minimize device damage:

Do not board wash or clean after the reflow process.

Do not brush board with or without solvents after the reflow process.

Do not directly expose to ultrasonic processing, welding, or cleaning.

Do not insert any object in port hole of device at any time.

Do not apply air pressure into the port hole.

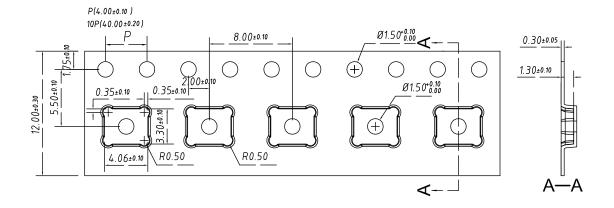
Do not pull a vacuum over port hole of the microphone.

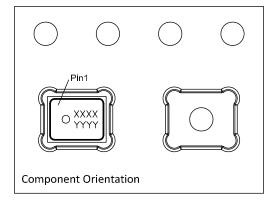
# **MATERIALS STATEMENT**

Meets the requirements of the European RoHS and Halogen-Free.



## **PACKAGING & MARKING DETAIL:**





Direction of Feed

## Note:

- 1) Dimensions are in mm;
- 2) Don't put the vacuum suction nozzle alignment the port hole;
- 3) Tape &Reel Per EIA-481 standard;
- 4) Label applied to external package and direct to reel;
- 5) Static voltage <100V;

Model Number	Reel Diameter	Quantity Per Reel
MSM421A3729H9-C	13 inch	5700



## **RELIABILITY SPECIFICATIONS**

Test	Description
Thermal Shock	100 cycles air-to-air thermal shock from -40°C to +125°C with 15 minute soaks. (IEC 68-2-4)
High Temperature Storage	1,000 hours at +105°C environment (IEC 68-2-2 Test Ba)
Low Temperature Storage	1,000 hours at -40°C environment (IEC 68-2-2 Test Aa)
Reflow	5 reflow cycles with peak temperature of +260°C
ESD-HBM/LID-GND	3 discharges of ±2 kV direct contact to I/O pins. (MIL 883E, Method 3015.7)& 3 discharges of ±8 kV direct contact to lid while unit is grounded. (IEC 61000-4-2)
Vibration	4 cycles of 20 to 2,000 Hz sinusoidal sweep with 20 G peak acceleration lasting 12 minutes in X, Y, and Z directions. (Mil-Std-883E, Method 2007.2 A)
Mechanical Shock	3 pulses of 10,000 G in the X, Y and Z direction (IEC 68-2-27, Test Ea)
High Temperature Bias	1,000 hours at +105°C under bias (IEC 68-2-2 Test Ba)
Low Temperature Bias	1,000 hours at -40°C under bias (IEC 68-2-2 Test Aa)
Temperature/Humidity Bias	1,000 hours at +85°C/85% R.H. under bias. (JESD22-A101A-B)
Drop Test	To be no interference in operation after dropped to 1.0cm steel plate  18 times from 1.5 meter height

**NOTE:**Sensitivity should vary within  $\pm 3$ dB from initial sensitivity. (The measurement to be done after 2 hours of conditioning at 20 $\pm 2$ °C, R.H 60% $\sim$ 70%)









Revision	Subjects (major changes since last revision)	Date
1.0	Initial Release	2016-10-25

公司销售、技术支持联系方式	(http://www.memsensing.com)	
For English:	中文用户:	
MEMSensing Microsystems Co. Ltd.	苏州敏芯微电子技术有限公司	
No. 99 Jinji Lake Avenue, Bldg. NW-09, Suite 501	苏州工业园区金鸡湖大道 99 号,NW-09 楼,501 室	
Suzhou Industrial Park, China 215123	中国 215123	
Phone: +86 512 62956055	电话: +86 512 62956055	
Fax: +86 512 62956056	传真: +86 512 62956056	
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